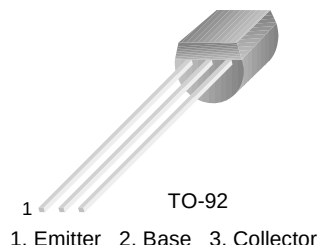


KSC815

KSC815

Low Frequency Amplifier & High Frequency Oscillator

- Collector-Base Voltage : $V_{CBO}=60V$
- Complement to KSA539
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	45	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	200	mA
P_C	Collector Power Dissipation	400	mW
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ C$

Electrical Characteristics $T_a=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	60			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=10mA, I_B=0$	45			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu A, I_C=0$	5			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=45V, I_E=0$			0.1	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=3V, I_C=0$			0.1	μA
h_{FE}	DC Current Gain	$V_{CE}=1V, I_C=50mA$	40		400	
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE}=10V, I_C=10mA$	0.6	0.65	0.9	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=150mA, I_B=15mA$		0.15	0.4	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=150mA, I_B=15mA$		0.83	1.1	V
f_T	Current Gain Bandwidth Product	$V_{CE}=10V, I_C=10mA$	100	200		MHz
C_{ob}	Output Capacitance	$V_{CB}=10V, I_E=0, f=1MHz$		4		pF

h_{FE} Classification

Classification	R	O	Y	G
h_{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400

Typical Characteristics

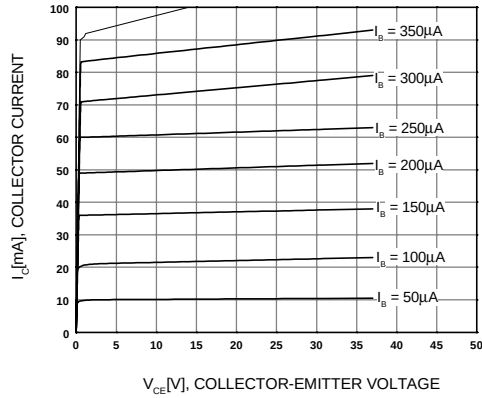


Figure 1. Static Characteristic

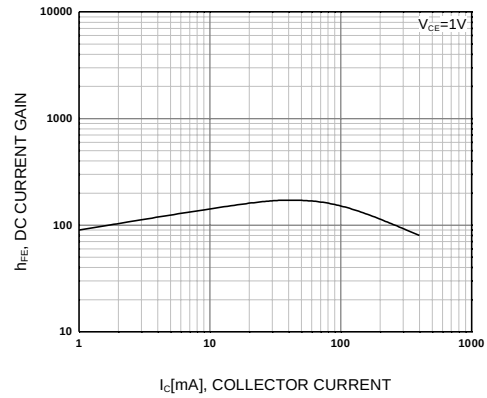


Figure 2. DC current Gain

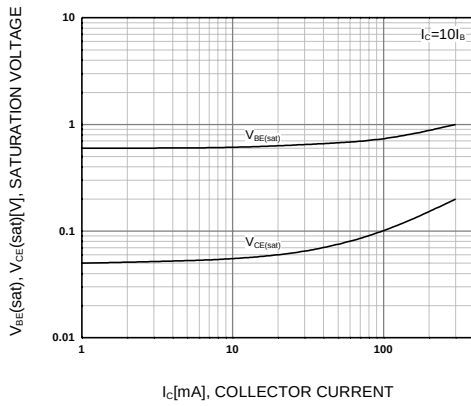


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

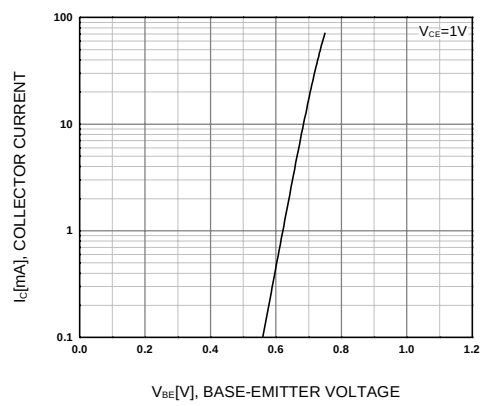


Figure 4. Base-Emitter On Voltage

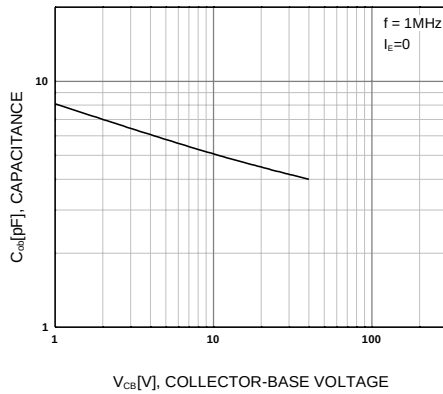


Figure 5. Collector Output Capacitance

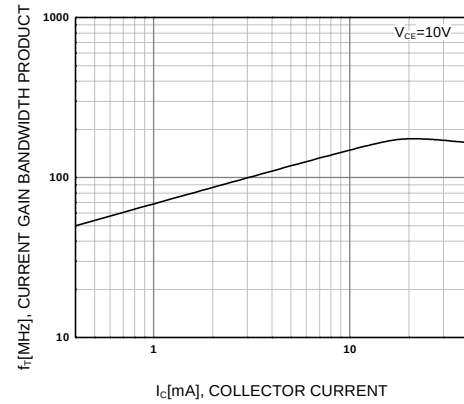
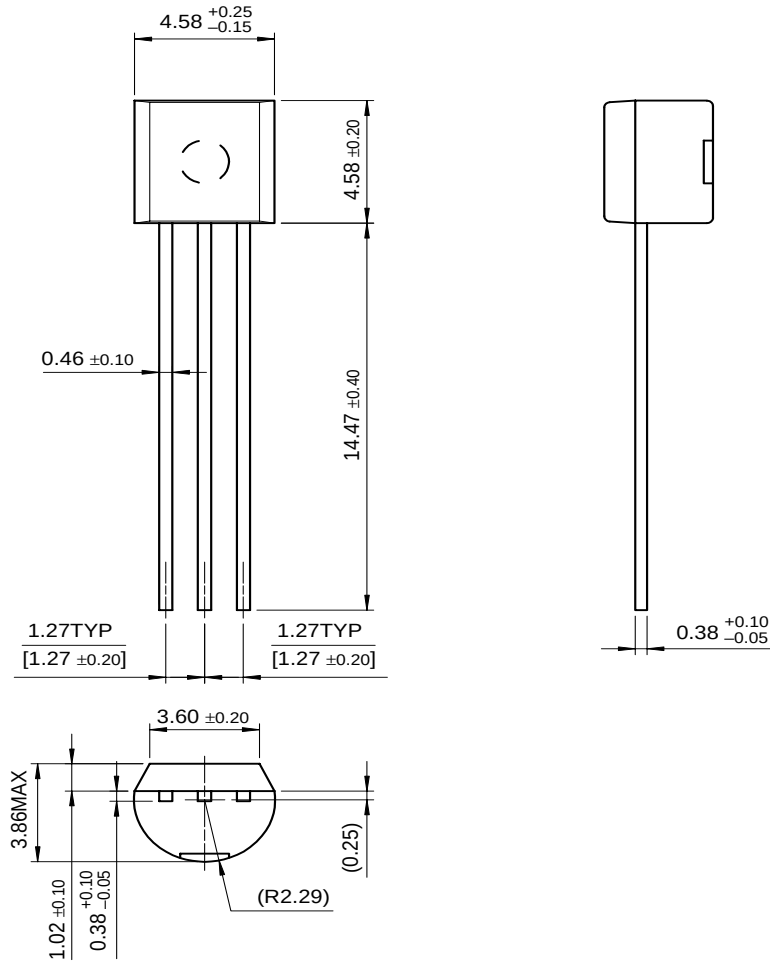


Figure 6. Current Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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